

DSS Infringement Contentions—Exhibit B
'552 Patent

	<p>Infringement Contentions for US 6,784,552</p> <p>Plaintiff DSS Technology Management Inc. (“DSS”) serves its Infringement Contentions as to Defendants Intel, A Conn’s, and Wal-Mart (“Defendants”). DSS contends that Defendants are each individually liable for infringement of claims 1-7.</p> <p>Intel has and continues to make, use, sell, import, and/or offer to sale in the United States systems and methods using semiconductor structures made via Intel’s 22-nanometer (“nm”) FinFET process (the “Accused Products”). The relevant sell, import, and/or offer to sale the Accused Products. DSS has attached a list of processors, known to it at this time, Intel’s 22-nm FinFET process. <i>See Exhibit 1.</i> These infringement contentions apply equally to any other Intel semiconductors made by an equivalent method with similar functionality, regardless of the specific product or process name.</p> <p>To date, the parties in this litigation have not engaged in any discovery, and no documents have been produced. All of these disclosures is the result of publicly available information and independent examination and analysis of the facts presented in these circumstances, DSS presents these Infringement Contentions reflecting DSS’s current analysis of the facts presented in the best of DSS’s knowledge, information, and belief, formed after an inquiry that is reasonable under the circumstances contained in this disclosure is correct. Certain information about the Accused Products operation is not available without discovery. Accordingly, DSS reserves the right to seek leave to supplement and/or amend these disclosures as new information and as DSS has the opportunity to review relevant Defendant document productions. Infringement investigation DSS anticipates that additional facts and relevant documents will be uncovered and disclosed that could create good supplementation and/or amendment of these contentions. DSS will continue to develop the evidence of infringement entities, and DSS reserves the right to amend and supplement these Infringement Contentions.</p> <p>Furthermore, based on DSS’s view that certain Defendant systems, products, processes, and/or services could infringe in multiple ways, DSS’s Infringement Contentions may include alternative theories of infringement for the Accused Products that are mutually exclusive of other infringement theories or which may overlap with other infringement theories in certain circumstances.</p> <p>Claim 1</p> <p>Infringement Evidence</p> <p>The Accused products contain semiconductor structures. Each of the 22 nanometer-process-based i3, i5, i7, Celero Xeon processors contains the infringing semiconductor structure. Unless otherwise noted, TEM images of a Core Atom, and Xeon processors —have the same gate-to-contact structures. Thus, those processors infringe as well.</p> <p>1. A structure, comprising:</p> <ul style="list-style-type: none">a) a conductive layer disposed over a substrate;
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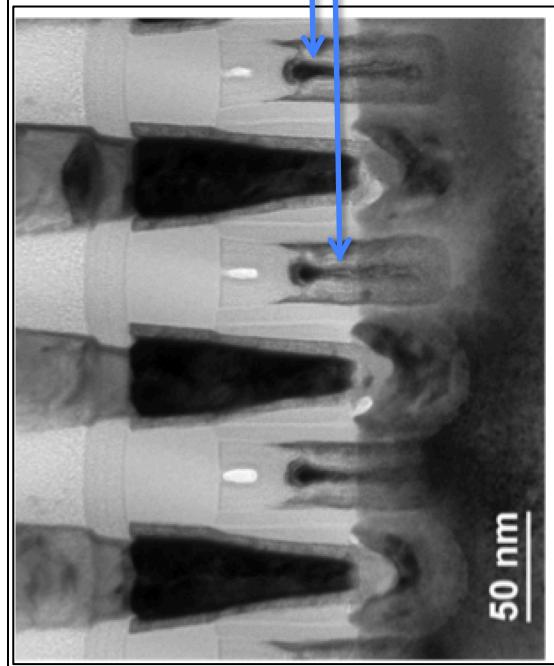
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Source: DSS2-0000755

The Accused Products have a conductive layer disposed over a substrate. The substrate, likely a silicon substrate, bottom of the below image. Conductive layers, the gates, are over the substrate. In the FinFET configuration where dimensional channel region, the gate is formed on top of the substrate, which includes the fin.

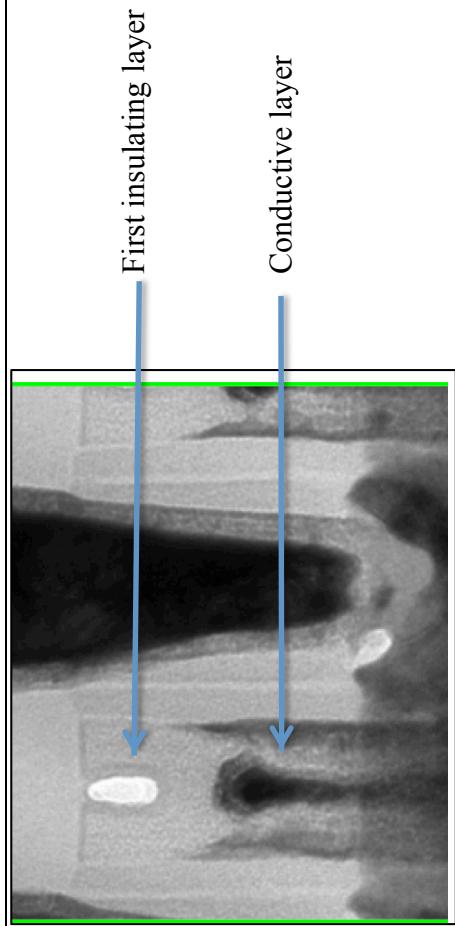
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Source: DSS2-0000751

- (b) a first insulating layer on the conductive layer:
- The Accused Products have a first insulating layer on the conductive layer. The first insulating layer is the light gray conductive gate layer with a white "bead" in the center.

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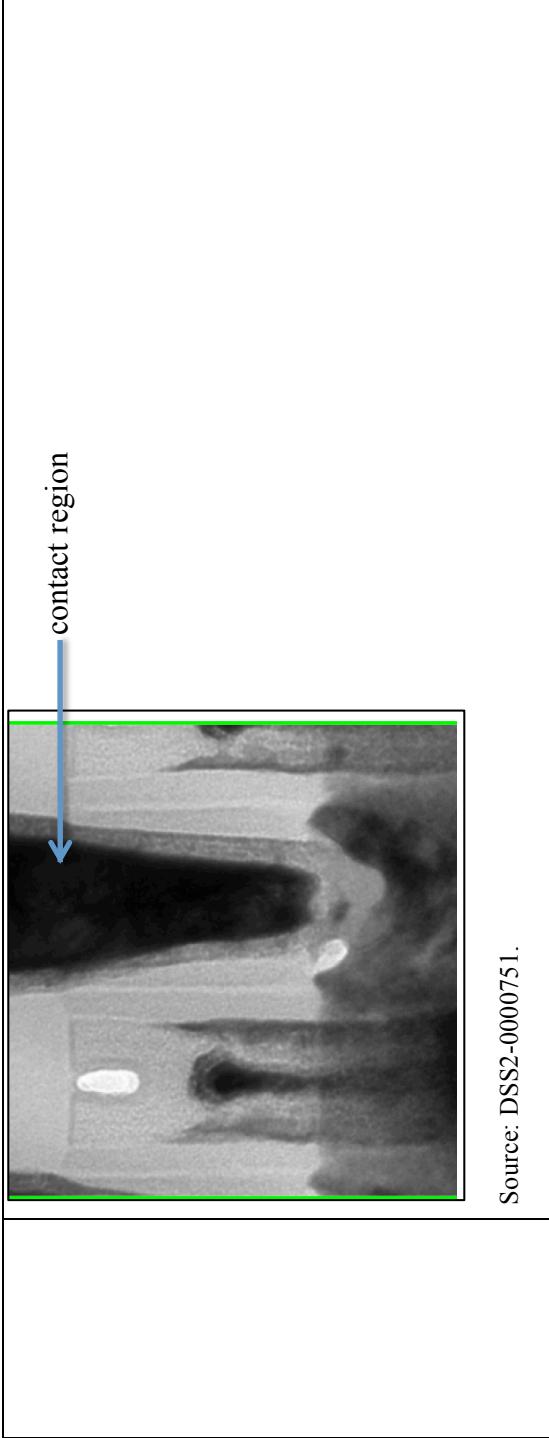
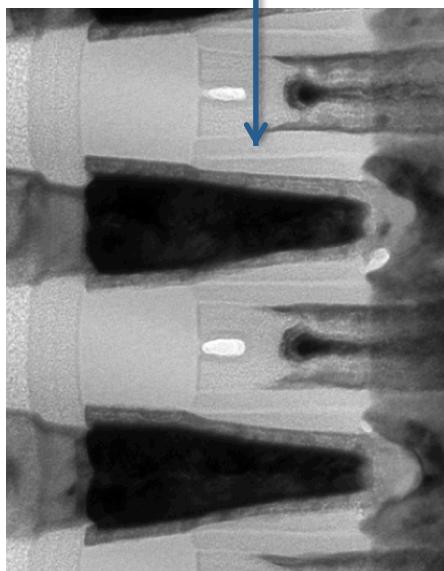


Source: DSS2-0000751.

(c) a contact region in said first insulating layer;

The Accused Products have a contact region in the first insulating layer. The contact region is the opening through which the contact is made to the substrate. Both “contact openings”—an opening through a dielectric exp an opening thorough a dielectric layer between polysilicon and a first metal layer—and “vias”—an opening in other opening through an intermetal dielectric layer—are “contact regions.” The contact region is shown as the dark reg of the picture to the diffusion region.

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 <p>A scanning electron micrograph (SEM) showing a contact region. A blue arrow points to the contact region, and a green rectangular box highlights a specific area. The contact region is a dark, vertical structure with a small white insulating spacer positioned within it.</p> <p>Source: DSS2-0000751.</p>	<p>(d) at least one insulating spacer in the contact region adjacent to the first insulating layer; and</p> <p>The Accused Products include at least one insulating spacer in the contact region. The insulating spacers are adjacent to the first insulating layer. The insulating spacers are the vertical, light grey materials on either side of the conductive layers.</p>  <p>A scanning electron micrograph (SEM) showing multiple contact regions. Blue arrows point to two specific contact regions, each containing a white insulating spacer. The contact regions are vertical conductive structures embedded in an insulating layer.</p> <p>Source: DSS2-0000751</p>
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